	Туре	Hits	Search Text	DBs
П	IS&R			USPAT
2	BRS	17	43719" "4292370" "4315668" "4339482" "47850" "4640584" "4695490" "4709991" "486442" "5106411" "5150239" "5188692" "518080" "5313322").PN.	USPAT
m	BRS	13	("4135789" "4222635" "4227779" "4297401" "4325610" "4388139" "4401537" "4418102" "4470668" "4494825" "4500171" "4514041" "4536060").PN.	USPAT
4	IS&R	0	1500171;4135789;4494825") or ("	USPAT
5	IS&R	9	(("4470668") or ("4500171") or ("4135789") or ("4494825") or ("4325610") or ("4536060")).PN.	USPAT
9	BRS	3650	cog or chip adj on adj glass same (control adj circuit\$ or semiconductor adj chip\$)	USPAT
7	BRS	3650	(cog or chip adj on adj glass same (control adj circuit\$ or semiconductor adj chip\$)) and ad<=19951219	USPAT
8	BRS	3650	cog or chip adj on adj glass near10(control adj circuit\$ or semiconductor adj chip\$)	USPAT
ത	BRS	116	(cog or chip adj on adj glass same (control adj circuit\$ or semiconductor adj chip\$)) and @ad<=19951219 and liquid adj crystal	USPAT
10	BRS	13	single?crystal adj silicon adj chip\$	USPAT

	Type	Hits	Search Text	DBs
11	BRS	1	single?crystal adj silicon adj chip\$ with (control adj circuit\$)	USPAT
12	BRS	4	1394067" "5148301" "5504348" "5610742").F	USPAT
13	BRS	4	("3807127" "3954325" "3961843" "4283118" "3807127" "3954325" "3961843" "4283118").PN.	USPAT
14	BRS	367	semiconductor adj chip\$ with (control adj circuit\$)	USPAT
15	BRS	3916	(control adj circuit or semiconductor adj chip\$) same seal\$5	USPAT
16	BRS	23	(semiconductor adj chip\$ with (control adj circuit\$)) and (control adj circuit or semiconductor adj chip\$) same seal\$5)	USPAT
17	BRS	195	semiconductor adj chip\$ with (control adj circuit\$)	US-PGPU B; EPO; JPO; DERWENT ; IBM TDB

	Туре	# 1	Hits	Search Text	DBs
Н	BRS	니	195	semiconductor adj chip\$ with (control adj circuit\$)	US-PGP UB; EPO; JPO; DERWEN T; IBM
7	BRS	L2	4	1 same seal\$5	US-PGP UB; EPO; JPO; DERWEN T; IBM
m	BRS	ГЗ	306	semiconductor adj chip\$ same (control adj circuit\$)	US-PGP UB; EPO; JPO; DERWEN T; IBM
4	BRS	L4	ω	3 same seal\$5	US-PGP UB; EPO; JPO; DERWEN T; IBM

	Type	#	Hits	Search Text	DBs
ഹ	BRS	1.5	179	1 @PD<=19951219	US-PGP UB; EPO; JPO; DERWEN T; IBM
ø	BRS	Ге			US-PGP UB; EPO; JPO; DERWEN T; IBM
7	BRS	L7	ĸ	5 and liquid adj crystal	US-PGP UB; EPO; JPO; DERWEN T; IBM

	D	1	Document ID	Issue Date	Pages	Title	Current OR
1		\boxtimes	US 4494825 A	19850122	9	Fill port seal with first and second photosensitizers	349/154
2		☒	US 4695490 A	19870922	9	Seal for liquid crystal display	428/1.53
<u></u> د			US 6091392 A	20000718	&	Passive matrix LCD with drive circuits at both ends of the scan electrode applying equal amplitude voltage waveforms simultaneously to	345/100
4		•	US 4394067 A	19830719	5	Display device	349/153
2			US 3954325 A	19760504	ഹ	Multilayer ceramic-based liquid crystal display	349/158
] 9			US 5849601 A	19981215	20	Electro-optical device and method for manufacturing the same	438/24
7		i i	JP 04192446 A	19920710	9	RESIN-SEALED SEMICONDUCTOR DEVICE	***************************************
8		•••••	JP 05113555 A	19930507	ഹ	LIQUID CRYSTAL DISPLAY UNIT	
	·			-	;		

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